

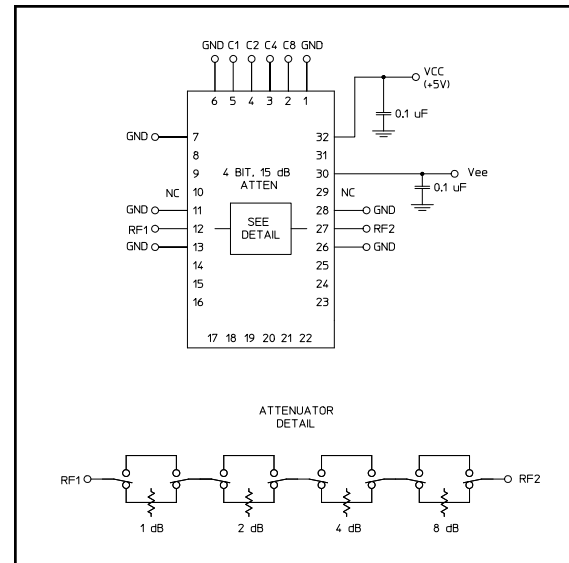
Features

- Attenuation: 1 dB Steps to 15 dB
- Low DC Power Consumption
- Small Footprint, JEDEC Package
- Integral TTL Driver
- 50 Ohm Impedance
- Test Boards Available
- Tape and Reel Packaging Available
- CSP-1 Package

Description

M/A-COM's AT90-0413 is a GaAs FET 4-Bit digital attenuator with integral driver. Step size is 1 dB providing a 15 dB attenuation range. This device is in an PQFN plastic surface mount package. The AT90-0413 is suited for applications where accuracy, fast speed, low power consumption and low costs are required.

Schematic with Off-Chip Components



Pin Configuration²

Pin No.	Function	Pin No.	Function
1	GND	17	N/C
2	C8	18	N/C
3	C4	19	N/C
4	C2	20	N/C
5	C1	21	N/C
6	GND	22	N/C
7	GND	23	N/C
8	N/C	24	N/C
9	N/C	25	N/C
10	N/C ¹	26	GND
11	GND	27	RF2
12	RF1	28	GND
13	GND	29	N/C ¹
14	N/C	30	-Vee
15	N/C	31	N/C
16	N/C	32	+Vcc

1. Pins 10 & 29 must be isolated.
2. The exposed pad centered on the package bottom must be connected to RF and DC ground. (For PQFN Packages)

Ordering Information

Part Number	Package
AT90-0413	Bulk Packaging
AT90-0413TR	1000 piece reel
AT90-0413-TB	Sample Test Board

Note: Reference Application Note M513 for reel size information.

Digital Attenuator

15.0 dB, 4-Bit, TTL Driver, DC-4.0 GHz

Rev. V7

Electrical Specifications: $T_A = 25^{\circ}\text{C}$

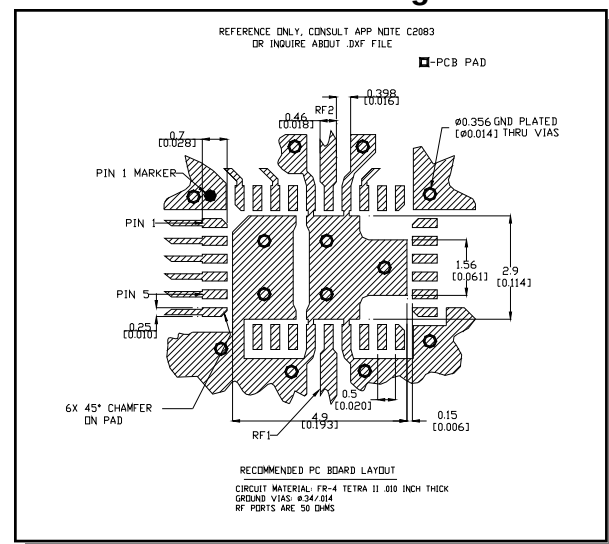
Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
Insertion Loss	—	DC-2.5 GHz DC-4.0 GHz	dB dB	— —	2.0 2.5	2.5 3.0
Attenuation Accuracy	Individual Bits or Combination of Bits	DC-2.5 GHz DC-4.0 GHz	dB dB	— —	— —	±(0.3+4% of atten setting) ±(0.3+6% of atten setting)
VSWR	Full Attenuation Range	DC-2.5 GHz DC-4.0 GHz	Ratio Ratio	— —	1.5:1 1.8:1	1.8:1 2.0:1
Switching Speed	50% Cntl to 90%/10% RF 10% to 90% or 90% to 10%	— —	nS nS	— —	75 20	150 50
1 dB Compression	—	50 MHz 0.5-4.0 GHz	dB dB	— —	+21 +29	— —
Input IP ₃	Two-tone Inputs up to +5 dBm	50 MHz 0.5-4.0 GHz	dB dB	— —	+35 +48	— —
+Vcc	—	—	V	4.75	5.0	5.25
-Vee	—	—	V	-8.0	-5.0	-4.75
V _{IL} V _{IH}	LOW-level input voltage HIGH-level input voltage	— —	V V	0.0 2.0	— —	0.8 5.0
I _{in} (Input Leakage Current)	V _{in} = V _{CC} or GND	—	uA	-1.0	—	1.0
I _{cc} (Quiescent Supply Current)	V _{cntrl} = V _{CC} or GND	—	uA	—	250	400
ΔI _{cc} (Additional Supply Current Per TTL Input Pin)	V _{CC} = Max, V _{cntrl} = V _{CC} - 2.1 V	—	mA	—	—	1.0
I _{EE}	V _{EE} min to max, V _{in} = V _{IL} or V _{IH}	—	mA	-1.0	-0.2	—
Thermal Resistance θ _{jc}	—	—	°C/W	—	15	—

Absolute Maximum Ratings^{3,4}

Parameter	Absolute Maximum
Max. Input Power 0.05 GHz 0.5 - 4.0 GHz	+27 dBm +34 dBm
V_{CC}	$-0.5V \leq V_{CC} \leq +7.0V$
V_{EE}	$-8.5V \leq V_{EE} \leq +0.5V$
$V_{CC} - V_{EE}$	$-0.5V \leq V_{CC} - V_{EE} \leq 14.5V$
V_{in}^5	$-0.5V \leq V_{in} \leq V_{CC} + 0.5V$
Operating Temperature	$-40^{\circ}C$ to $+85^{\circ}C$
Storage Temperature	$-65^{\circ}C$ to $+125^{\circ}C$

3. Exceeding any one or combination of these limits may cause permanent damage to this device.
4. M/A-COM does not recommend sustained operation near these survivability limits.
5. Standard CMOS TTL interface, latch-up will occur if logic signal applied prior to power supply.

Recommended PCB Configuration⁶



6. Application Note S2083 is available on line at www.macom.com

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

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Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Moisture Sensitivity

The MSL rating for this part is defined as Level 2 per IPC/JEDEC J-STD-020. Parts shall be stored and/or baked as required for MSL Level 2 parts.

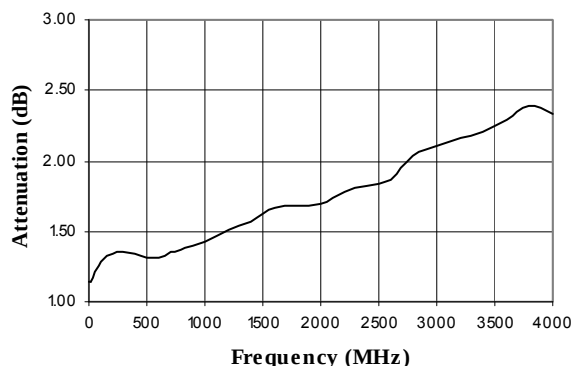
Truth Table (Digital Attenuator)

C8	C4	C2	C1	Attenuation
0	0	0	0	Loss, Reference
0	0	0	1	1.0 dB
0	0	1	0	2.0 dB
0	1	0	0	4.0 dB
1	0	0	0	8.0 dB
1	1	1	1	15.0 dB

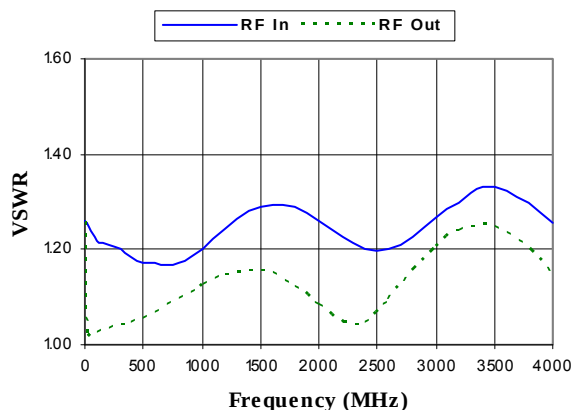
0 = TTL Low. 1 = TTL High

Typical Performance Curves

Insertion Loss

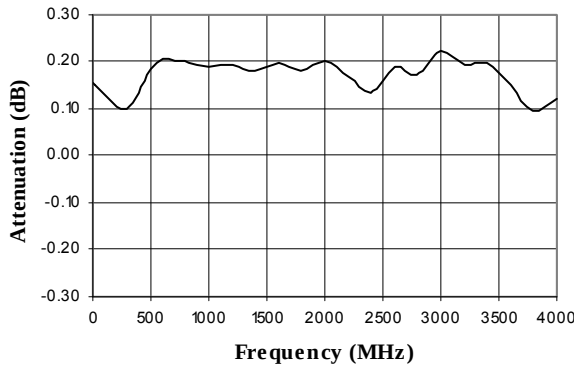


VSWR @ Insertion Loss

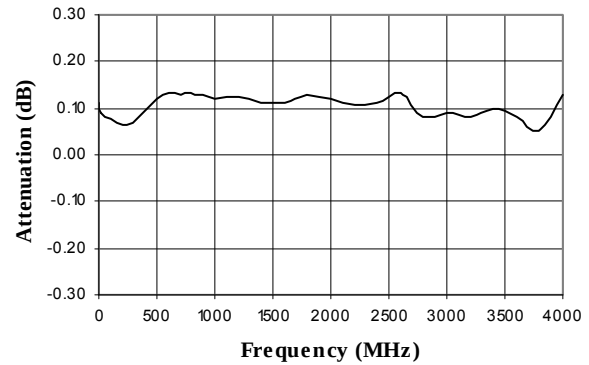


Typical Performance Curves

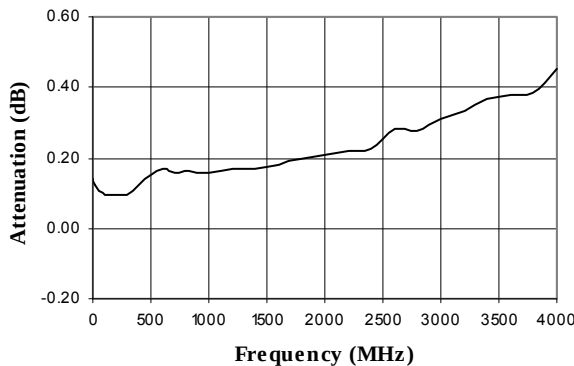
Attenuation Error, 1 dB Bit



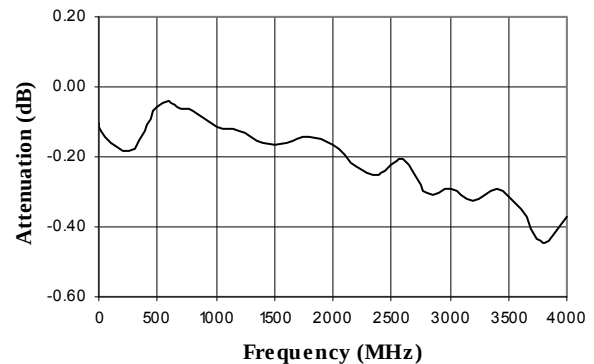
Attenuation Error, 2 dB Bit



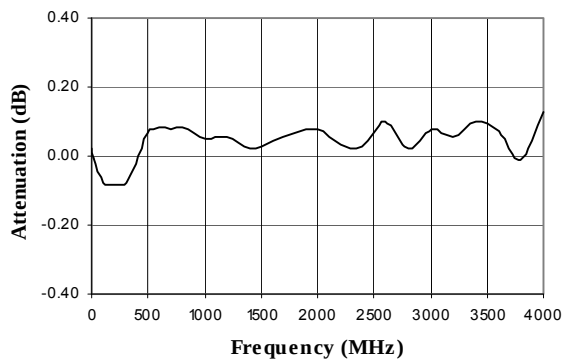
Attenuation Error, 4 dB Bit



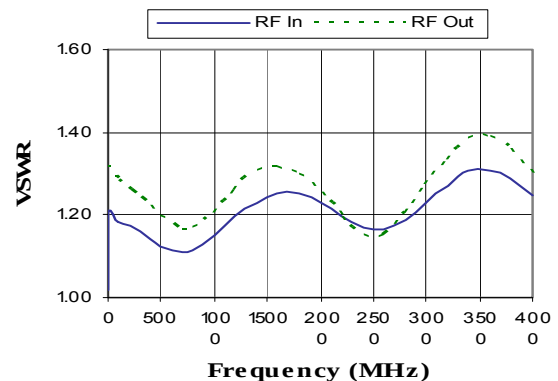
Attenuation Error, 8 dB Bit



Attenuation Error, Max. Attenuation

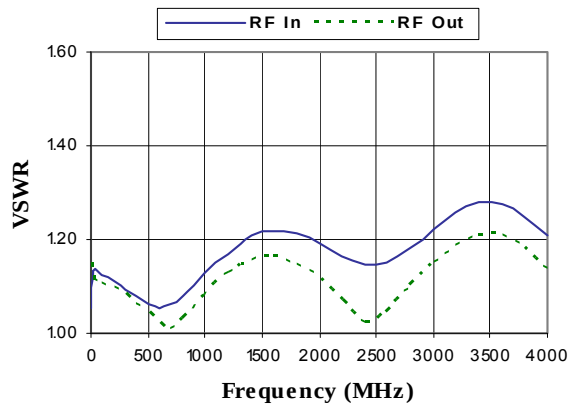


VSWR, 1 dB Bit

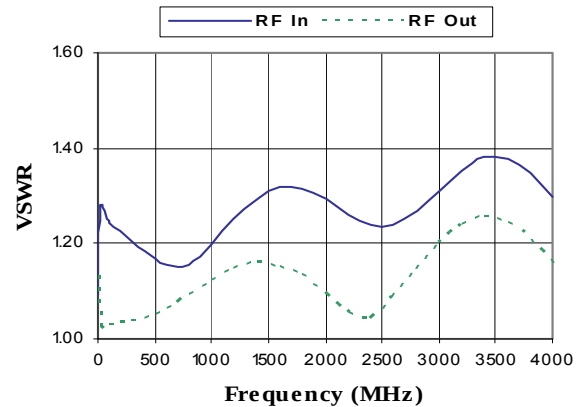


Typical Performance Curves

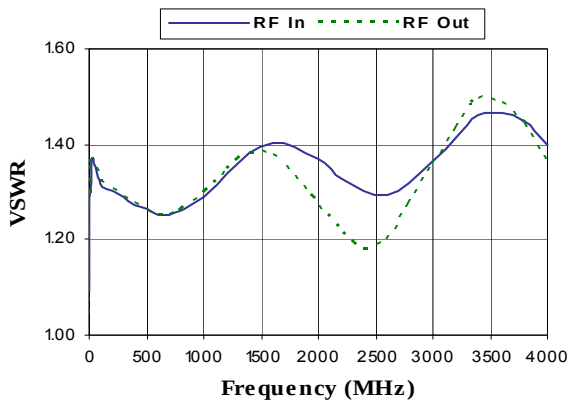
VSWR, 2 dB Bit



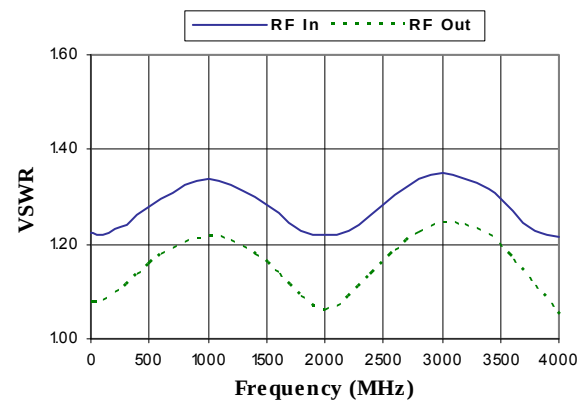
VSWR, 4 dB Bit



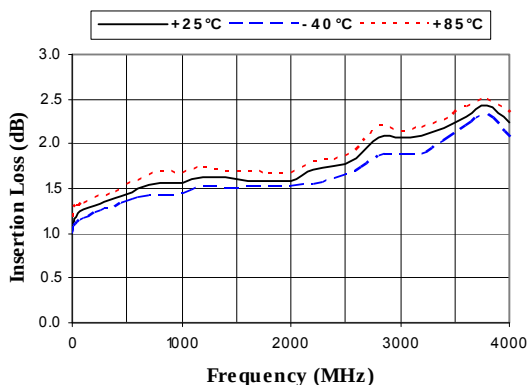
VSWR, 8 dB Bit



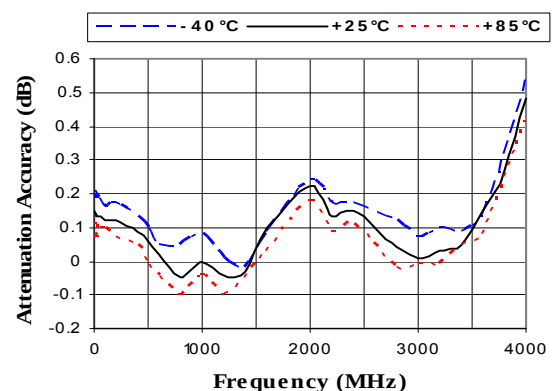
VSWR, Max. Attenuation



Insertion Loss vs. Temperature

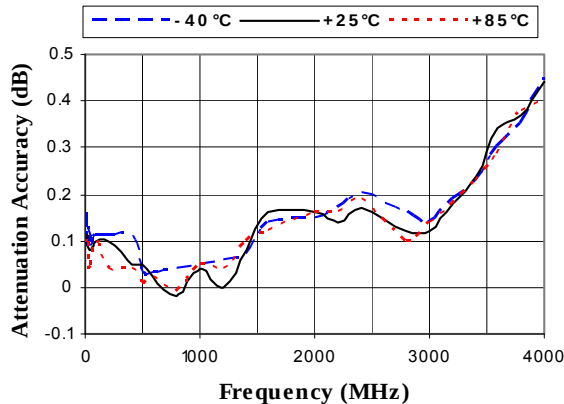


1 dB Bit vs. Temperature

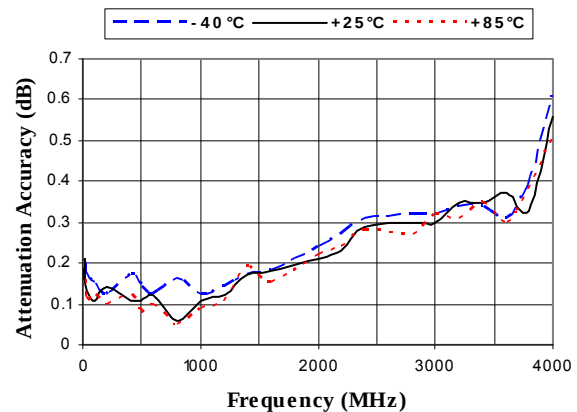


Typical Performance Curves

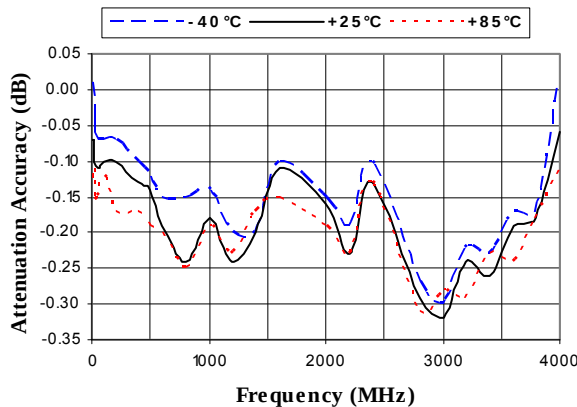
2 dB Bit vs. Temperature



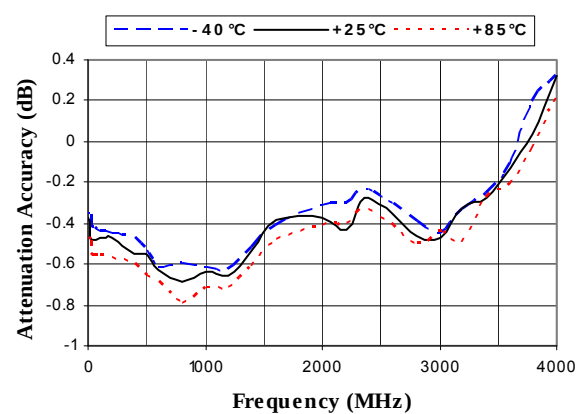
4 dB Bit vs. Temperature



8 dB Bit vs. Temperature



Max. Attenuation vs. Temperature

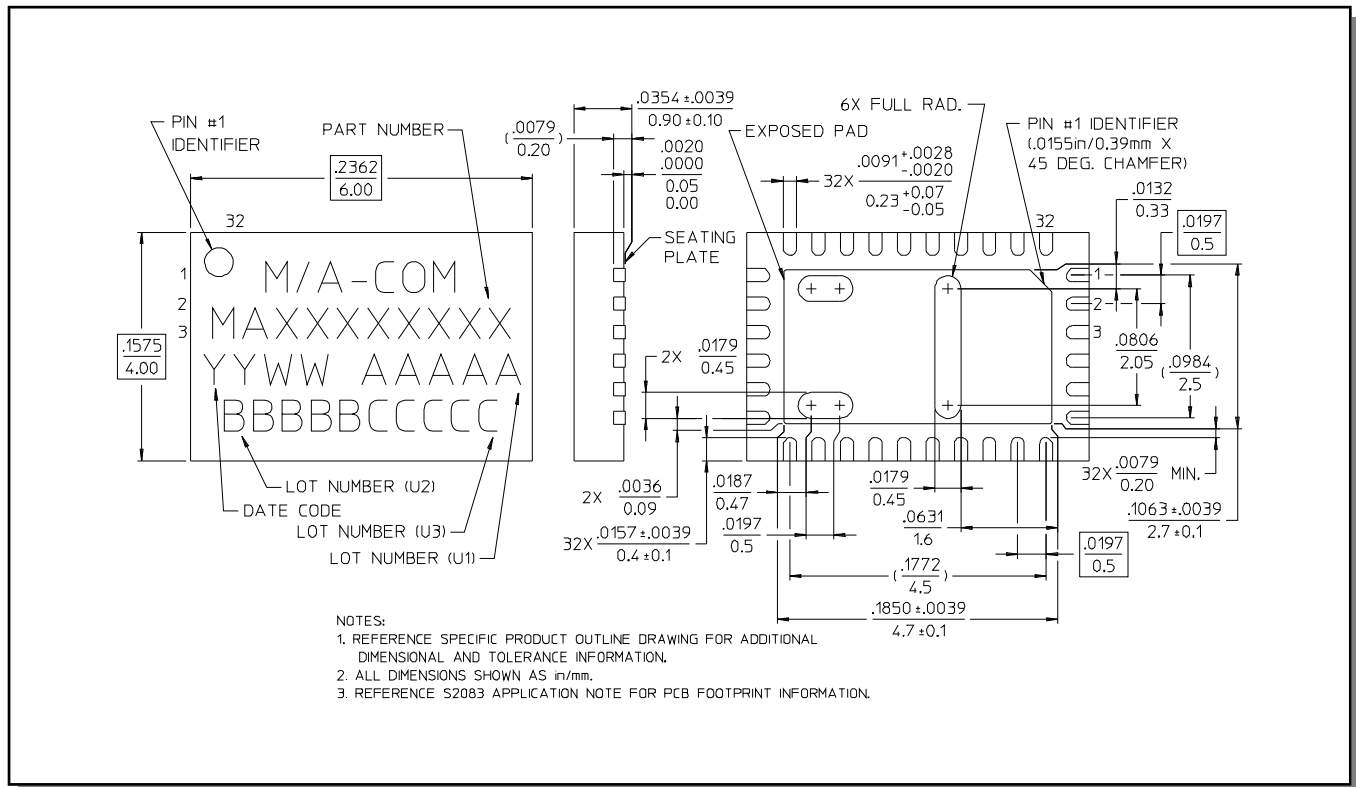


Digital Attenuator

15.0 dB, 4-Bit, TTL Driver, DC-4.0 GHz

Rev. V7

CSP-1, 4 x 6 mm, 32-lead PQFN[†]



[†] Reference Application Note M538 for lead-free solder reflow recommendations.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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